**New Product** 



### SiP2100

Vishay Siliconix

## 5 V, 1 A H-Bridge Motor Driver

#### DESCRIPTION

The SIP2100 is an integrated, buffered H-bridge with TTL and CMOS compatible inputs with the capability of delivering up to 1 A continuous current at 5 V V<sub>DD</sub> supply.

The SIP2100 has two independent logic inputs that can set four different motor operation modes: normal rotation, reverse rotation, stop (idling) and braking. The internal shoot-through protection logic also prevents upper and lower outputs from being turned on simultaneously.

The SiP2100 offers high efficiency with an extremely low operating current. The device also benefits from over temperature protection with a shut down hysteresis of 20 °C. The SIP2100 is available in SOIC8 package.

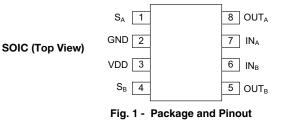
### **FEATURES**

- 1 A drive capability
- Optimized for 5 V V<sub>DD</sub> bias
- Extremely low idle current
- Shoot-through protection scheme
- Thermal shutdown
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

#### **APPLICATIONS**

- High performance servo
- Optical/tape disk drives
- Brush/stepper motor driver

### **PACKAGE OUTLINE**



### FUNCTIONAL BLOCK DIAGRAM AND TRUTH TABLE

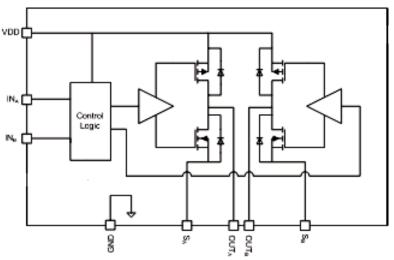


Fig. 2 - Functional Block Diagram

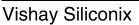
TRUTH TABLE			
IN <sub>A</sub>	IN <sub>B</sub>	OUT <sub>A</sub>	Out <sub>B</sub>
1	0	1	0
0	1	0	1
0	0	0	0
1	1	HiZ	HiZ

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For technical questions, contact: powerictechsupport@vishay.com



COMPLIANT HALOGEN FREE





ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C, unless otherwise noted)					
Electrical Parameter	Conditions	Limits	Unit		
V <sub>DD</sub>	Reference to GND	- 0.3 to 6			
OUT <sub>A</sub> , OUT <sub>B</sub>	Reference to GND	- 0.3 to 6	v		
S <sub>A</sub> , S <sub>B</sub>	Reference to GND	- 0.3 to 1	v		
IN <sub>A</sub> , IN <sub>B</sub>	Reference to GND	- 0.3 to V <sub>DD</sub>			
Temperature					
Operating Temperature - 40 to 85		°C			
Max. Operating Junction Temperature		150			

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating/conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS					
Parameter	Min.	Тур.	Max.	Unit	
V <sub>DD</sub>	3.8	5	5.5	V	
Temperature					
Operating Junction Temperature	0		125	0°	
Recommended Ambient Temperature	0		70		

THERMAL RESISTANCE RATINGS					
Parameter		Max.	Unit		
Thermal Pagistance (Junction to Ambient)	SO-8, R <sub>thJA</sub>	153	°C/W		
Thermal Resistance (Junction to Ambient)	SO-8 PowerPAD, R <sub>thJC</sub>	40	C/W		
Power Dissipation	SO-8, T <sub>A</sub> = 70 °C	522	mW		
	SO-8 PowerPAD, T <sub>A</sub> = 70 °C	2	W		
Junction Temperature		- 65 to 150	°C		
Storage Temperature	- 55 to 150				

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	Cumhal	Test Conditions		Limits				
Parameter	Symbol	V <sub>DD</sub>	$V_{DD} = 5 V$		Typ. <sup>b</sup>	Max. <sup>a</sup>	Unit	
Driver Power Supply	·			•		•		
		IN = 10	00 kHz		250	300		
V <sub>DD</sub> Bias Supply Current	I <sub>DD</sub>	IN = 2	0 kHz		150	180	μA	
		Quiesce	ent state		50			
V <sub>DD</sub> Rising Threshold	V <sub>DD TH_R</sub>	V <sub>DD</sub>	rising		2.8	3	v	
V <sub>DD</sub> Falling Threshold	V <sub>DD TH_F</sub>	V <sub>DD</sub> f	falling	2	2.5		v	
V <sub>DD</sub> UVLO Hysteresis	V <sub>DD UVLO</sub>				300		mV	
Input Logic				<u>.</u>				
Input Voltage High	VIN <sub>H</sub>			2				
Input Voltage Low	VINL					0.7	V	
Input Sourcing Current	I <sub>INH</sub>					1	μΑ	
Input Sinking Current	I <sub>INL</sub>			- 1				
Output Stage								
Output Voltage High	V <sub>OUTH</sub>	I <sub>OUT</sub> = - 500 mA		4.4				
Output Voltage High	VOUTH	I <sub>OUT</sub> = - 1000 mA	V <sub>DD</sub> = 4.75 V	4.25			v	
	V <sub>OUTL</sub>	I <sub>OUT</sub> = + 500 mA				0.25		
Output Voltage Low	VOUTL	I <sub>OUT</sub> = + 1000 mA				0.5		
Output High Propagation Delay	TP <sub>LH</sub>				20	25	nS	
Output Low Propagation Delay	TP <sub>HL</sub>				20	25	113	
Thermal Protection		• •		•	•	•		
Thermal Shutdown Threshold					150		°C	
Thermal Shutdown Hysteresis					20		Ŭ	

Notes:

a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.

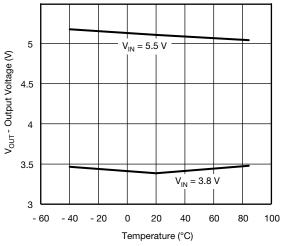
b. Guaranteed by design, not subject to production testing.

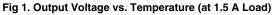
PIN DESCRIPTION (SOIC PACKAGE)				
Pin Number	Name	Function		
1	S <sub>A</sub>	Driver output return A		
2	GND	Analog ground of internal logic		
3	V <sub>DD</sub>	Input of internal logic bias and power stage		
4	S <sub>B</sub>	Driver output return B		
5	OUT <sub>B</sub>	Driver output B		
6	IN <sub>B</sub>	Driver input B		
7	IN <sub>A</sub>	Driver input A		
8	OUT <sub>A</sub>	Driver output A		





### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





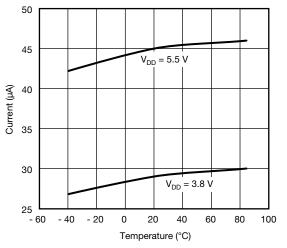
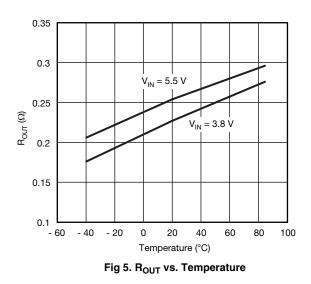


Fig 3. Quiescent Current vs. Temperature



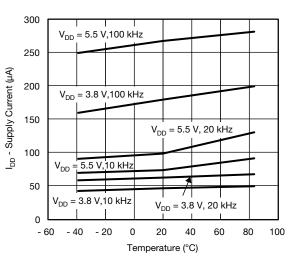


Fig 2. Supply Current I<sub>DD</sub> vs. Temperature

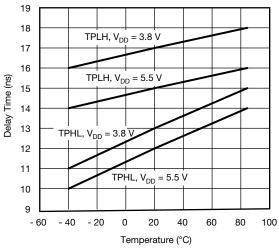
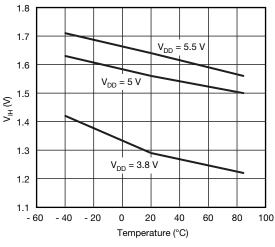


Fig 4. Propagation Delay vs. Temperature





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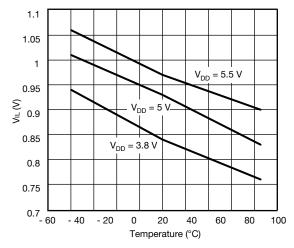


Fig 7. PWM Falling Threshold vs. Temperature

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?63949">www.vishay.com/ppg?63949</a>.



## Package Information

Vishay Siliconix

# SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012





	MILLIMETERS		INCHES		
DIM	Min	Мах	Min	Max	
A	1.35	1.75	0.053	0.069	
A <sub>1</sub>	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
E	3.80	4.00	0.150	0.157	
е	1.27 BSC		0.050 BSC		
н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	
S	0.44	0.64	0.018	0.026	
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498					



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